

SMA6F5.0A thru SMA6F20A

Vishay General Semiconductor

Rohs

HALOGEN

FREE

Surface Mount TRANSZORB® Transient Voltage Suppressors



PRIMARY CHARACTERISTICS						
V _{WM}	5.0 V to 20 V					
P _{PPM} (10 x 1000 μs)	600 W					
P _{PPM} (8 x 20 μs)	4000 W					
P _D at T _M = 55 °C	6 W					
T _J max.	175 °C					

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, and telecommunication.

FEATURES

- Very low profile typical height of 0.95 mm
- Ideal for automated placement
- Uni-directional only
- · Excellent clamping capability
- · Peak pulse power:
 - 600 W (10/1000 μs)
 - 4 kW (8/20 µs)
- ESD capability: IEC 61000-4-2 level 4
 - 15 kV (air)
 - 8 kV (contact)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: DO-221AC (SlimSMA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	VALUE	UNIT				
Dock pulse power dissipation	with a 10/1000 µs waveform	P _{PPM} ⁽¹⁾	600	W			
Peak pulse power dissipation	with a 8/20 µs waveform	FPPM (*)	4000	VV			
Poak pulco current	with a 10/1000 µs waveform	I _{PPM} ⁽¹⁾	See next table	Α			
Peak pulse current	with a 8/20 µs waveform	IPPM ***	See Hext table	ζ			
Power dissipation	T _M = 55 °C	P _D ⁽²⁾	6	W			
rower dissipation	T _A = 25 °C	P _D ⁽³⁾	1.0	VV			
Storage temperature range	T _{STG}	T _{STG} - 65 to + 175					
Operating junction temperature range	T_J	- 55 to + 175	°C				

Notes

- $^{(1)}$ Non-repetitive current pulse, per fig. 3 and derated above T_A = 25 $^{\circ}$ C per fig. 2.
- (2) Power dissipation mounted on infinite heatsink
- (3) Power dissipation mounted on minimum recommended pad layout



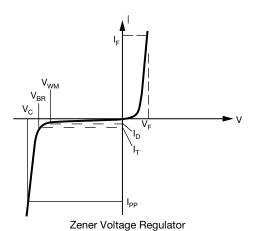
V_F

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ELECTRICAL CHARACTERISTICS							
SYMBOL PARAMETER							
V _{WM}	Stand-off voltage						
V _{BR}	Breakdown voltage						
V _C	Clamping voltage						
I _D	Leakage current at V _{WM}						
I _{PP}	Peak pulse current						
αΤ	Voltage temperature coefficient						
V _F	Forward voltage drop						

Dynamic resistance



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)														
		RR	BREAKDOWN		MAXIMUM		V _C AT I _{PP} R _D ⁽²⁾		V _C AT I _{PP} F		R _D (2)	αΤ (3)		
DEVICE TYPE	DEVICE MARKING CODE	V	OLTAG	E	REVERSE LEAKAGE I _D AT V _{WM} ⁽³⁾)/1000 µs		8/20 µs					
		MIN.	MAX.		25 °C	85 °C		MAX.			MAX.			MAX.
		'	V	mA	μ	A	٧	٧	Α	Ω	٧	Α	Ω	10 ⁻⁴ /°C
SMA6F5.0A	6AE	6.40	7.07	10	150	375	5.0	9.2	68.0	0.031	13.4	298	0.021	5.7
SMA6F6.0A	6AG	6.70	7.41	10	600	1500	6.0	9.5	63.2	0.033	13.7	290	0.022	5.9
SMA6F6.5A	6AK	7.20	7.96	10	100	250	6.5	10.2	58.8	0.038	14.5	276	0.024	6.1
SMA6F7.5A	6AP	8.33	9.21	1	50	125	7.5	11.8	50.8	0.051	17.0	235	0.033	6.5
SMA6F8.0A	6AR	8.89	9.83	1	20	50	8.0	12.8	46.9	0.063	18.2	220	0.038	7.0
SMA6F8.5A	6AT	9.4	10.4	1	20	50	8.5	13.3	45.1	0.064	18.7	205	0.040	7.3
SMA6F10A	6AX	11.1	12.3	1	1.0	5.0	10	15.7	38.2	0.089	19.6	184	0.040	7.8
SMA6F11A	6AZ	12.2	13.5	1	1.0	5.0	11	17.2	34.8	0.107	21.5	172	0.047	8.1
SMA6F12A	6BE	13.3	14.7	1	0.2	1.0	12	18.8	31.9	0.128	23.5	157	0.056	8.3
SMA6F12AHD	6BF	13.2	14.3	1	0.2	1.0	12	18.5	32.4	0.130	22.9	157	0.055	8.4
SMA6F13A	6BG	14.4	15.9	1	0.2	1.0	13	20.4	29.4	0.153	23.9	147	0.064	8.4
SMA6F15A	6BM	16.7	18.5	1	0.2	1.0	15	23.6	25.4	0.201	27.7	123	0.075	8.8
SMA6F16A	6BP	17.8	19.7	1	0.2	1.0	16	25.2	23.8	0.229	29.5	119	0.082	8.8
SMA6F17A	6BR	18.9	20.9	1	0.2	1.0	17	26.7	22.5	0.259	31.4	111	0.095	9.0
SMA6F18A	6BT	20.0	22.1	1	0.2	1.0	18	28.3	21.2	0.292	33.2	102	0.109	9.2
SMA6F20A	6BV	22.2	24.5	1	0.2	1.0	20	31.4	19.1	0.361	36.8	93	0.132	9.4

Notes

- (1) Pulse test: $t_p \le 50 \text{ ms}$
- To calculate maximum clamping voltage at other surge currents, use following formula: V_{CL} max. = $R_D \times I_{PP} + V_{BR}$ max.
- (3) To calculate V_{BR} vs. junction temperature, use following formula: V_{BR} at T_J = V_{BR} at 25 °C x (1 + αT x (T_J 25))

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER SYMBOL VALUE UNIT							
Typical thermal resistance, junction to ambient	R _{0JA} (1)	150	°C/W				
Typical thermal resistance, junction to mount $R_{\theta JM}^{(2)}$ 20 °C/W							

Notes

- (1) Mounted on minimum recommended pad layout
- (2) Mounted on infinite heatsink



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IMMUNITY TO STATIC ELECTRICAL DISCHARGE TO THE FOLLOWING STANDARDS (T _A = 25 $^{\circ}$ C unless otherwise noted)								
STANDARD	TEST TYPE TEST CONDITIONS SYMBOL CLASS VALUE							
IEC 61000-4-2	Human body model (contact mode)	$C = 150 \text{ pF}, R = 330 \Omega$	V	4	> 8 kV			
IEC 61000-4-2	Human body model (air discharge mode)	C = 150 pr, h = 350 Ω	V _C	4	> 15 kV			

ORDERING INFORMATION (Example)								
PREFERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE BASE QUANTITY DELIVERY MODE								
SMA6F5.0A-M3/6A	0.032	6A	3500	7" diameter plastic tape and reel				
SMA6F5.0A-M3/6B	0.032	6B	14 000	13" diameter plastic tape and reel				

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

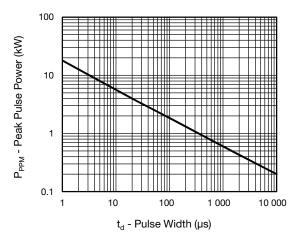


Fig. 1 - Peak Pulse Power Rating Curve

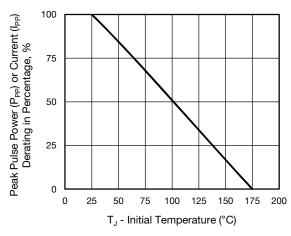


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

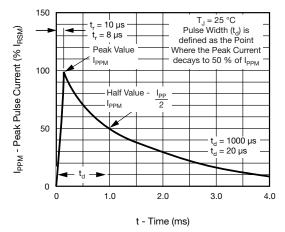
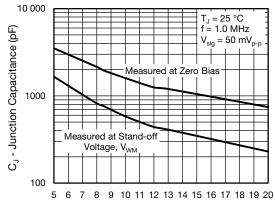


Fig. 3 - Pulse Waveform



V_{WM} - Reverse Stand-Off Voltage (V)

Fig. 4 - Typical Junction Capacitance



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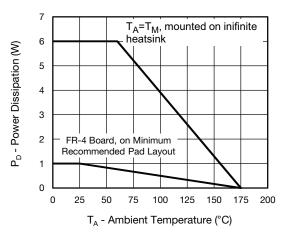


Fig. 5 - Power Dissipation Derating Curve

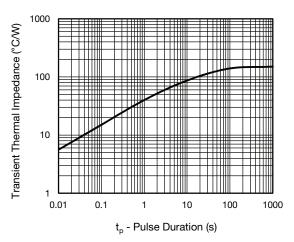
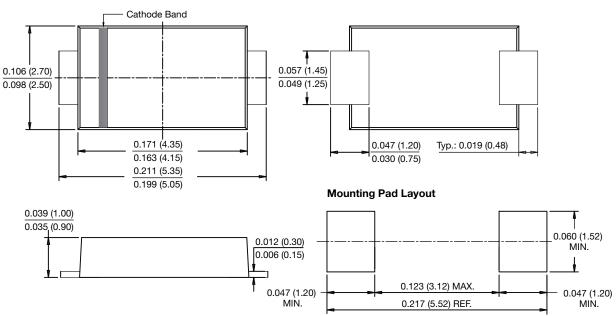


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-221AC (SlimSMA)





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